

SONY

SLD233VL

Index-Guided High Power AlGaAs Laser Diode

Description

The SLD233VL is a high power index-guided AlGaAs laser diode.

Features

- Low noise
- Low power consumption

Applications

Pickups for MiniDisc recording/playback

Structure

- AlGaAs quantum well-structure laser diode
- PIN photodiode for optical power output monitor

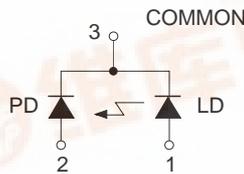
Recommended Operating Optical Power Output

30mW

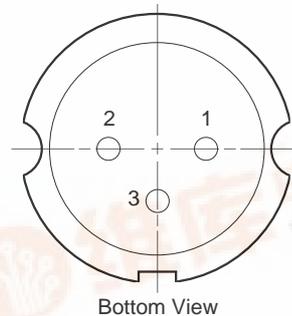
Absolute Maximum Ratings (Tc = 25°C)

- Optical power output Po 35 mW
- Reverse voltage VR LD 2 V
PD 15 V
- Operating temperature Topr -10 to +60 °C
- Storage temperature Tstg -40 to +85 °C

Connection Diagram



Pin Configuration



- 1. LD ANODE
- 2. PD ANODE
- 3. COMMON

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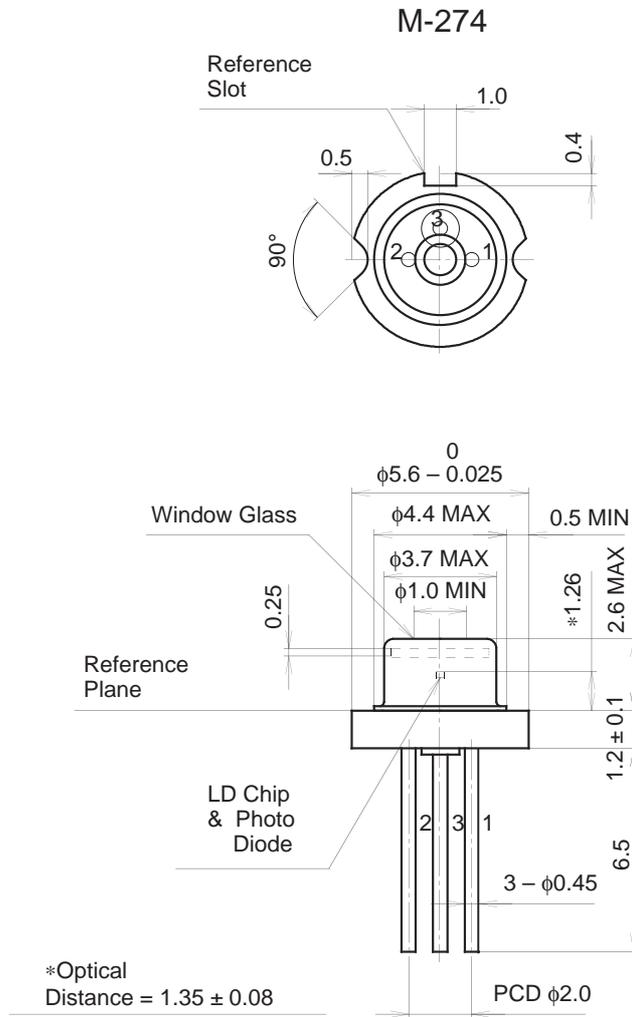
Optical and Electrical Characteristics (Tc = 25°C)

Tc: Case temperature

Item	Symbol	Conditions	Min.	Typ.	Max.	Unit	
Threshold current	I _{th}			30	40	mA	
Operating current	I _{op}	P _o = 35mW		70	85	mA	
Operating voltage	V _{op}	P _o = 35mW		2.0	2.5	V	
Oscillation wavelength	λ	P _o = 35mW	780	790	800	nm	
Radiation angle	Perpendicular	θ _⊥	P _o = 35mW	26	28.5	32	degree
	Parallel	θ _{//}		7.4	8.5	10.0	degree
Positional accuracy	Position	ΔX, ΔY, ΔZ	P _o = 35mW			±80	μm
	Angle	Δφ _⊥				±3	degree
		Δφ _{//}				±2	degree
Differential efficiency	η _D	P _o = 30mW	0.55	0.9	1.2	mW/mA	
Astigmatism	As			-16		μm	
Coherence	γ	P _o = 4mW		0.7	0.9		

Package Outline

Unit: mm



SONY CODE	M-274
EIAJ CODE	_____
JEDEC CODE	_____

PACKAGE WEIGHT	0.3g
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